Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.185 inches

Terminal Length:

0.365 inches

Overall Diameter:

0.430 inches

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 repetitive peak reverse voltage, peak total value

Current Rating Per Characteristic:

8.00 amperes forward current, dc

Power Rating Per Characteristic:

0.5 watts small-signal input power, common-collector peak

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Test Data Document:

17863-7117140 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 insulated wire lead w/terminal lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0